





Micron Technology




MT47H512M4THN-25E:M

Part Number:	MT47H512M4THN-25E:M
Manufacturer/Brand:	Micron Technology
Product description	IC DRAM 2G PARALLEL 400MHZ
Datasheets:	 MT47H512M4THN-25E:M.pdf
RoHs Status	 Lead free / RoHS Compliant
Stock Condition	3876 pcs stock
Ship From	Hong Kong
Shipment Way	DHL/Fedex/TNT/UPS/EMS

REQUEST FOR QUOTATION

Specifications of MT47H512M4THN-25E:M

PART NUMBER	MT47H512M4THN-25E:M
MANUFACTURER	Micron Technology
DESCRIPTION	IC DRAM 2G PARALLEL 400MHZ
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
QUANTITY AVAILABLE	3876 pcs
DATA SHEET	 MT47H512M4THN-25E:M.pdf
WRITE CYCLE TIME - WORD, PAGE	15ns
VOLTAGE - SUPPLY	1.7 V ~ 1.9 V
TECHNOLOGY	SDRAM - DDR2
SERIES	-
OPERATING TEMPERATURE	0°C ~ 85°C (TC)
MOISTURE SENSITIVITY LEVEL (MSL)	3 (168 Hours)
MEMORY TYPE	Volatile
MEMORY SIZE	2Gb (512M x 4)
MEMORY INTERFACE	Parallel
MEMORY FORMAT	DRAM
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DETAILED DESCRIPTION	SDRAM - DDR2 Memory IC 2Gb (512M x 4) Parallel 400MHz 400ps
CLOCK FREQUENCY	400MHz
ACCESS TIME	400ps

Related Tags

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 <div>MT47H512M4THN-25E:H Manufacturers: Micron Technology Description: IC DRAM 2G PARALLEL 63FBGA In stock: 4134 pcs <div>RFQ</div></div>	 <div>MT47H512M4THN-25E:M TR Manufacturers: Micron Technology Description: IC DRAM 2G PARALLEL 63FBGA In stock: 4157 pcs <div>RFQ</div></div>
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 <div>MT47H32M8BP-5E:B TR Manufacturers: Micron Technology Description: IC DRAM 256M PARALLEL 60FBGA In stock: 11658 pcs <div>RFQ</div></div>	 <div>MT47H512M8WTR-25E:C TR Manufacturers: Micron Technology Description: IC DRAM 4G PARALLEL 63FBGA In stock: 1678 pcs <div>RFQ</div></div>